

Contents lists available at ScienceDirect

Solar Energy Materials & Solar Cells



journal homepage: www.elsevier.com/locate/solmat

Improvement of photovoltaic performance of perovskite solar cells with a ZnO/Zn_2SnO_4 composite compact layer



Weixin Li^{a,b,c}, Qinghui Jiang^{a,b}, Junyou Yang^{a,b,*}, Yubo Luo^{a,b}, Xin Li^{a,b}, Yaru Hou^{a,b}, Shuqin Zhou^{a,b}

^a State Key Laboratory of Materials Processing and Die & Mould Technology, Huazhong University of Science and Technology, No. 1037 Luoyu Road, Wuhan 430074, PR China

^b Shenzhen Institute of Huazhong University of Science and Technology, PR China

^c Hubei Province Key Laboratory of Refractories and Ceramics & Ministry-Province Jointly-Constructed Cultivation Base for State Key Laboratory, Wuhan University of Science and Technology, No. 947 Heping Avenue, Wuhan 430081, PR China

University of Science and reenhology, No. 547 Treping Tvenae, Wahan 450001, TK enha

ARTICLE INFO

Article history: Received 27 May 2016 Received in revised form 15 July 2016 Accepted 9 September 2016 Available online 15 September 2016

Keywords: Perovskite Compact layer Solar cell

ABSTRACT

In this study, ZnO/Zn_2SnO_4 (ZSO) composite is synthesized as a promising alternative compact layer to TiO_2 by spray pyrolysis method. Owing to the ZnO/ZSO composite possesses higher carrier mobility and suitable band gap structure, it will behave well in the application of solar cells. The characterization results show that the ZnO/ZSO composite compact layer manifests better optical transmittance, enhanced electrons collective efficiency and superior electrical conductivity. Consequently, the corresponding photo-current is improved effectively when compared with that of TiO₂ compact layer. The optimum efficiency of perovskite solar cell based on the ZnO/ZSO composite compact layer reaches 12.03% at AM 1.5 solar light of 100 mW cm⁻², which is 18% higher than that of perovskite solar cell based on the TiO₂ compact layer.

© 2016 Published by Elsevier B.V.

1. Introduction

Due to their intrinsic optimum band gap of 1.55 eV, high absorption coefficient ($> 10^4 \text{ cm}^{-1}$), long hole-electron diffusion length (100-1000 nm) and superior ambipolar carrier transport properties, the organic/inorganic hybrid perovskite materials have been proved to be excellent light energy harvesters [1–4]. Since the organic/inorganic hybrid perovskite solar cell (PSC) was reported by Miyasaka [5] in 2009, a research boom of PSC has up surged around the world, and a power conversion efficiency exceeding 20% has been reported recently [6-8]. Typically, a perovskite solar cell is assembled like a sandwich structure with solid light absorber layer between efficient electron selective contacts and hole transporting materials (HTM) [9,10]. According to the cell structure, the perovskite solar cells can be classified into two types, namely the mesoporous and the planar heterojunction solar devices, both of which could be fabricated via single step, two sequential and vapor deposition methods [11–13].

The general working mechanism of PSC based on mesoporous TiO_2 is similar to that of dye-sensitized solar cells. Namely, an

* Corresponding author at: State Key Laboratory of Materials Processing and Die & Mould Technology, Huazhong University of Science and Technology, No. 1037 Luoyu Road, Wuhan 430074, PR China.

E-mail address: jyyang@mail.hust.edu.cn (J. Yang).

http://dx.doi.org/10.1016/j.solmat.2016.09.007 0927-0248/© 2016 Published by Elsevier B.V. electron in perovskite is excited from the valence band to the conduction band under solar irradiance, followed by the injection of the electron into TiO_2 and hole into the HTM layer with the circuit completed by transporting the electron in TiO_2 via the external circuit to recombine with holes at the counter electrode [14]. Based on the mechanism stated above, the compact electron transport layer plays a critical role in facilitating electrons transportation and suppressing recombination between the FTO and HTM layer [15–17]. In this regard, tremendous efforts have been made on exploiting suitable compact layers (CLs) for effective charge separation and carrier extraction [18]. Choi and Song et al. have studied the relationship between the morphology of a conventional TiO_2 layer on the FTO and the electron transport properties [19].

However, the TiO₂ CL commonly used in PSC behaves poor in electron extraction owing to its relatively low carrier mobility [20]. Hence, semiconductors with larger carrier mobility have also been employed as the alternative CLs like SnO₂ and ZnO [21–23]. Dong et al. [24] reported a higher short-circuit in the PSC based on a SnO₂ CL fabricated by the sol-gel method than that of the PSC based on a TiO₂ CL. Liu et al. [12] applied a ZnO nanoparticle film as the CL in the PSC and achieved the efficiency of 15.7%. Besides, Zn₂SnO₄ (ZSO) as a spinel structure compound has always been adopted as a transport-conducting oxide for optoelectronic applications due to its high stability and electron mobility [25].

Actually, owing to its higher charge injection and electron diffusion efficiency than that of TiO₂ [26], ZSO is also a very promising alternative to the TiO₂ CL in PSC. Recently, Oh et al. [27] adopted the spin-coating method to fabricate a ZSO CL and the PSC based on the 300 nm thick mesoporous ZSO layer manifests a PCE of 7%. Given that composite electrodes combine two semiconductors into one thus they can compensate each other, electrodes such as TiO₂-ZnO, SnO₂-TiO₂, and ZnO-Zn₂SnO₄ have been applied in dye-sensitized solar cells and quantum dots sensitized solar cells to enhance the photovoltaic performance [28]. Thereby, a composite CL, which has rarely been adopted in PSC, would also be beneficial to its photovoltaic performance.

In this scenario, we fabricated a composite ZnO/ZSO CL through a facile spray pyrolysis route to replace the traditional TiO₂ CL in PSCs in this paper. Considering ZnO possesses a superior electronic mobility of 205–300 cm² V s⁻¹ than that of ZSO with 10– 15 cm² V s⁻¹ [29,30], ZnO can effectively facilitate the transportation of electrons. On the other side, the inherent larger band gap with higher conduction band edge of ZSO benefits for restricting the recombination process and improving the open-circuit voltage. Given that the energy band structure is similar with that of TiO₂ and the mobility of TiO₂ is less than $1 \text{ cm}^2 \text{V}^{-1} \text{S}^{-1}$ [31,32], it is expected that the ZnO/ZSO composite CL may exhibit a superior photovoltaic performance in contrast with that based on a conventional TiO₂ CL. The effects of the composite ZnO/ZSO CL on the performance of PSCs have been investigated, and the electron dynamics of the ZnO/ZSO-based perovskite solar cells have been compared with the conventional TiO₂-based counterpart. The results demonstrate that the PSC based on composite ZnO/ZSO CL manifests better photovoltaic performance than that of the PSC based on TiO₂ CL.

2. Experimental section

2.1. Reagents and materials

Lead iodide (99.999% trace metals basis) and N,N-dimethyl formamide (DMF) were purchased from Alfa Aesar. Li-bis-(*tri*-fluoromethanesulfonyl) imide (Li-TFSI), 4-*tert*-butylpyridine (TBP) and methylamine (33 wt% in absolute ethanol) were purchased from Aladdin Reagents. Hydroiodic acid (57 wt% in water, 99.99%) was purchased from Sigma-Aldrich. Titanium (IV) acetylacetonate (75% in isopropanol) was purchased from TCI in Japan. Spiro-OMeTAD (2,2',7,7'-tetrakis(N,N-di-4-methoxyphenylamino)-9,9'-spriobifluorene, 99.0%) and TiO₂ pastes were obtained from Wuhan Jingge Technology of Solar Cell Co., Ltd. Isopropanol, n-butyl alcohol, ZnCl₂, SnCl₄, zinc powder, ethanol were purchased from Sinopharm Chemical Reagent Co., Ltd. (China). All of the used reagents were analytical grade without further purification.

2.2. Synthesis of TiO_2 and ZnO/ZSO compact layer on transparent conducting substrate

Fluorine-doped SnO₂-coated transparent conduction glass substrates (FTO) were etched with metallic Zn powder and HCl (2 M), then cleaned with ethanol, acetone and deionized water under an ultrasonic condition for 30 min, lastly dried in an oven. To remove the organic impurities, the FTO substrates were annealed at 500 °C for 30 min. Different compact layers were deposited on each FTO substrate using the spray-pyrolysis method. For TiO₂ compact layer, a solution containing 100 µL titanium (IV) acetylacetonate in 1 mL n-butyl alcohol was sprayed on the cleaned FTO substrates which were placed on a hot plate with 450 °C. After spraying, the compact layer was kept at 450 °C for 30 min on the hot plate. To deposit the ZnO/ZSO layer, solution containing ZnCl₂ and SnCl₄ (mole ratio of Zn/Sn is 2) in isopropanol was adopted with the same spray-pyrolysis process of synthesis TiO₂ layer. Lastly, the obtained ZnO/ZSO layer was annealed at 600 °C for 30 min under flow N₂ atmosphere. For TiO₂ mesoporous layer, a commercial TiO₂ paste (20 nm) was diluted with ethanol (1:3 wt ratio), and spin-coated on the CL coated FTO substrate, followed by annealing at 500 °C for 30 min under an ambient atmosphere.

2.3. Device fabrication

CH₃NH₃I was synthesized as described earlier [33] via reacting 30 mL of methylamine and 32.3 mL of hydroiodic acid in a 250 mL round bottom flask at 0 °C for 2 h with continuously stirring. The precipitate was recovered by putting the solution in the vacuum oven under 60 °C for 6 h. The obtained raw product of methylammonium iodide (CH₃NH₃I) was washed with diethylether until the powder become white. After filtration, the solids were collected and dried at 60 °C in a vacuum oven for 24 h. The synthesis of CH₃NH₃PbI₃ on the mesoporous TiO₂ surface was carried out by a two-step deposition method [11] and we did some modification to optimize the morphology of CH₃NH₃PbI₃. At the beginning, a 460 mg mL⁻¹ PbI₂ solution dissolved in N,N-dimethyl formamide (DMF) was dropped onto the TiO₂ film and spin coated at 3000 rpm for 60 s, followed by annealing at 70 °C for 30 min. In the second step, the cell was dipped into a beaker containing 10 mg mL^{-1} CH_3NH_3I solution (dissolved in isopropanol) and then the whole beaker was put on the hot plate at 70 °C for 10 min. After that, the film was taken out and washed with isopropanol followed by annealing at 70 °C for another 30 min. During the dipping and annealing, CH₃NH₃PbI₃ was formed, as indicated by the dark brown color of the electrode. Subsequently, the spiroOMeTAD based hole transporting layer which contained 72.3 mg of spiroOMeTAD, 28.8 µL of 4-tert-butylpyridine and 17.5 µL of Libis-(tri-fluoromethanesulfonyl) imide (Li-TFSI) solution (520 mg of Li-TFSI in 1 mL of acetonitrile), all dissolved in 1 mL of chlorobenzene, was deposited onto the perovskite-coated substrate by spin coating at 3000 rpm for 60 s. Finally, 80 nm of gold was deposited through thermal evaporation as the counter electrode. The cells were characterized under an Air Mass 1.5 Global (AM 1.5 G) solar simulator with an irradiation intensity of 100 mW cm⁻² and the active area was 0.1 cm².

2.4. Characterization

X-ray diffraction (XRD) patterns were recorded with a Philip X'pert X-ray diffractometer equipped with Cu K α irradiation (λ 1.5406 Å). The morphology were observed through a Nova Nano-SEM 450 field emission scanning electron microscope (FE-SEM). The square average roughness of CL was characterized by the atomic force microscope (AFM, SPM9700, Shimadzu). UV-vis light absorption spectra were recorded with a Lambda 35 (Perkin Elmer) ultraviolet visible (UV-vis) spectrophotometer. The photoluminescence spectrum was obtained by a VG Multilab 2000 X-ray photoelectron spectroscopy (XPS). The photovoltaic measurements of the PSCs were performed with the aid of a CHI604D electrochemical workstation under a simulated sunlight (Chang Tuo, incident light intensity 100 mW cm⁻²). The internal impedance of the PSCs were measured by electrochemical impedance spectroscopy (EIS) using an Autolab PGSTAT 30 equipment (Eco Chemie B.V., Utrecht, The Netherlands) with the frequency ranging from 0.01 Hz to 100 kHz at room temperature under dark condition with the applied bias voltage and AC amplitude of 0.8 V and 10 mV, respectively.

Download English Version:

https://daneshyari.com/en/article/6457463

Download Persian Version:

https://daneshyari.com/article/6457463

Daneshyari.com